

**N-Channel Enhancement Mode MOSFET****• Features**

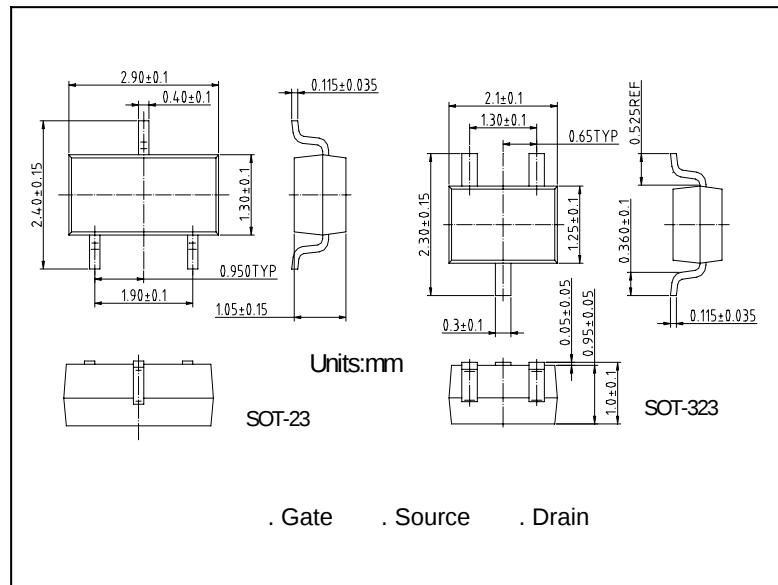
- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Low voltage drive (2.5V) makes this device ideal for portable equipment.
- 4) Easily designed drive circuits.
- 5) Easy to parallel.

• Applications

Interfacing, switching (30V, 100mA)

• Structure

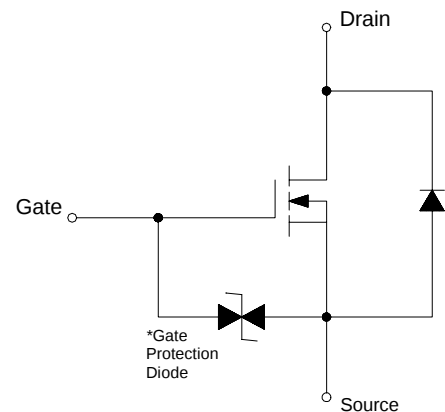
Silicon N-channel
MOSFET

• External dimensions**• Absolute maximum ratings (Ta = 25°C)**

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	30	V
Gate-source voltage		V_{GSS}	20	V
Drain current	Continuous	I_D	100	mA
	Pulsed	I_{DP*1}	200	mA
Reverse drain current	Continuous	I_{DR}	100	mA
	Pulsed	I_{DRP*1}	200	mA
Total power dissipation(Tc=25°C)		P_{D*2}	200	mW
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55~+150	°C

*1Pw ≤ 10μs, Duty Cycle ≤ 50%

*2With each pin mounted on the recommended lands

• Equivalent circuit

*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use a protection circuit when the fixed voltages are exceeded.

N-Channel Enhancement Mode MOSFET

• Electrical characteristics (Ta = 25°C)

Parameter	Symbo	Min.	Typ.	Max.	Unit	Test Conditions
Gate-source leakage	I_{GSS}	----	----	± 1	μA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DS}$	30	----	----	V	$I_D=10\mu A, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	----	----	1	μA	$V_{DS}=30V, V_{GS}=0V$
Gate threshold Voltage	$V_{GS(th)}$	0.8	----	1.5	V	$V_{DS}=3V, I_D=100\mu A$
Static drain-source on-state resistance	$R_{DS(ON)}$	----	5	8	Ω	$I_D=10mA, V_{GS}=4V$
	$R_{DS(ON)}$	----	7	13	Ω	$I_D=1mA, V_{GS}=2.5V$
Forward transfer admittance	Y_{fs}	20	----	----	mS	$V_{DS}=3V, I_D=10mA$
Input capacitance	C_{iss}	----	13	----	pF	$V_{DS}=5V$
Output capacitance	C_{oss}	----	9	----	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	----	4	----	pF	$F=1\text{ MHz}$
Turn-on delay time	$t_{d(on)}$	----	15	----	ns	$I_D=10\text{ mA}, V_{DO}=5V$
Rise time	t_r	----	35	----	ns	$V_{GS}=5V$
Turn-off delay time	$t_{d(off)}$	----	80	----	ns	$R_L=500\Omega$
Fall time	t_f	----	80	----	ns	$R_{GS}=10\Omega$

• Electrical characteristic curves

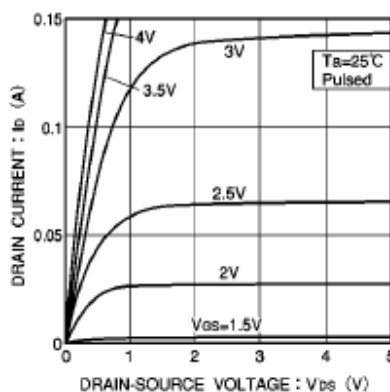


Fig.1 Typical output characteristics

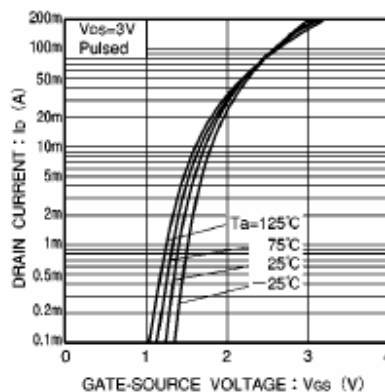


Fig.2 Typical transfer characteristics

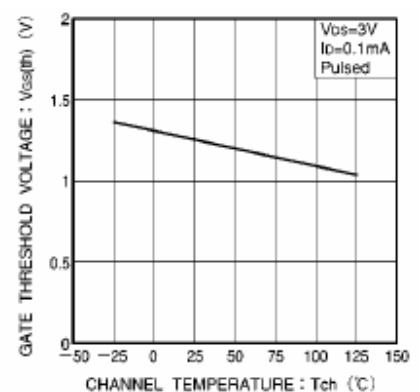


Fig.3 Gate threshold voltage vs. channel temperature

N-Channel Enhancement Mode MOSFET

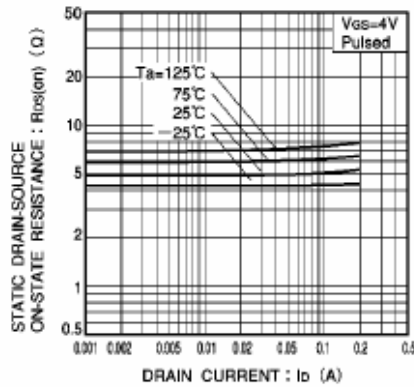


Fig.4 Static drain-source on-state resistance vs. drain current (I)

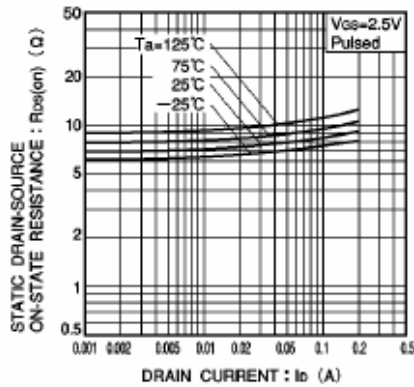


Fig.5 Static drain-source on-state resistance vs. drain current (II)

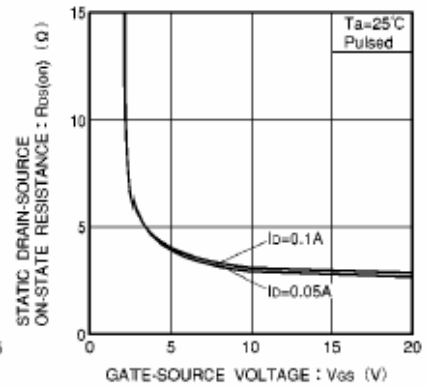


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

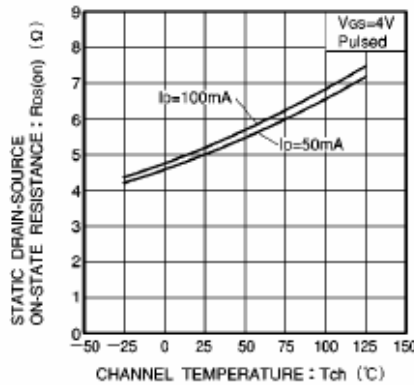


Fig.7 Static drain-source on-state resistance vs. channel temperature

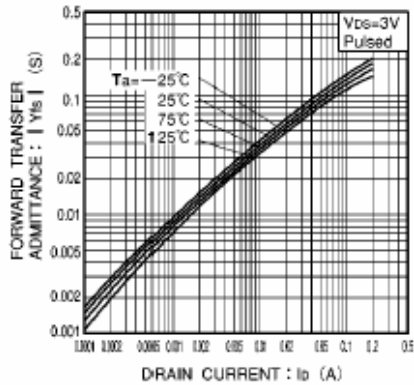


Fig.8 Forward transfer admittance vs. drain current

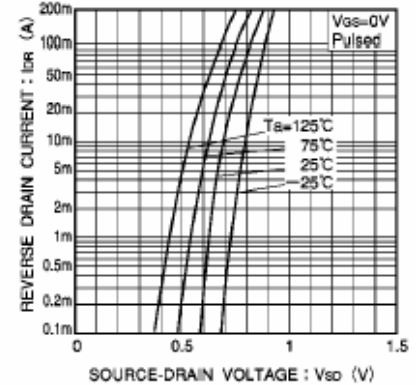


Fig.9 Reverse drain current vs. source-drain voltage (I)

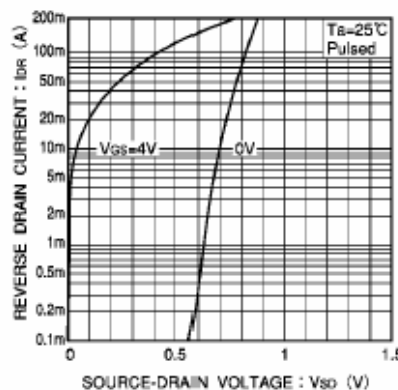


Fig.10 Reverse drain current vs. source-drain voltage (II)

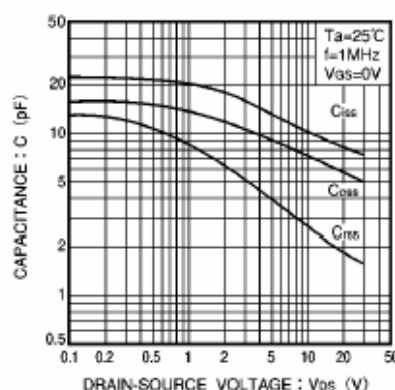


Fig.11 Typical capacitance vs. drain-source voltage

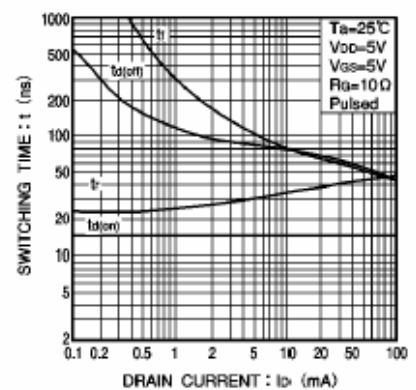


Fig.12 Switching characteristics (See Figures. 13 and 14 for the measurement circuit and resultant waveforms)

N-Channel Enhancement Mode MOSFET

- Switching characteristics measurement circuit

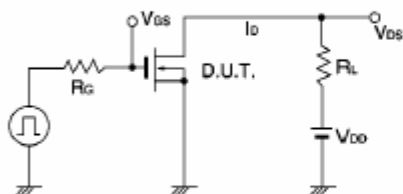


Fig.13 Switching time measurement circuit

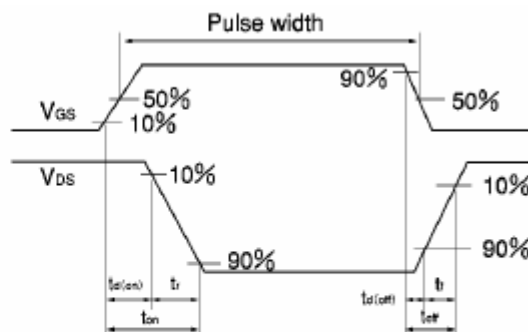


Fig.14 Switching time waveforms

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [Jinyu](#) manufacturer:

Other Similar products are found below :

[614233C](#) [648584F](#) [MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [FW216A-TL-2W](#) [FW231A-TL-E](#) [APT5010JVR](#) [NTNS3A92PZT5G](#)
[IRF100S201](#) [JANTX2N5237](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [FCA20N60_F109](#) [FDZ595PZ](#) [STD6600NT4G](#) [FSS804-TL-E](#) [2SJ277-DL-E](#)
[2SK1691-DL-E](#) [2SK2545\(Q,T\)](#) [D2294UK](#) [405094E](#) [423220D](#) [MCH6646-TL-E](#) [TPCC8103,L1Q\(CM](#) [367-8430-0972-503](#) [VN1206L](#)
[424134F](#) [026935X](#) [051075F](#) [SBVS138LT1G](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [751625C](#) [873612G](#) [IRF7380TRHR](#)
[IPS70R2K0CEAKMA1](#) [RJK60S3DPP-E0#T2](#) [RJK60S5DPK-M0#T0](#) [APT5010JVFR](#) [APT12031JFLL](#) [APT12040JVR](#) [DMN3404LQ-7](#)
[NTE6400](#) [JANTX2N6796U](#) [JANTX2N6784U](#) [JANTXV2N5416U4](#) [SQM110N05-06L-GE3](#) [SIHF35N60E-GE3](#)